Dramatic Role of Critical Current Anisotropy on Flux Avalanches in MgB_2 Films

J. Albrecht and A. T. Matveev*

Max-Planck-Institut für Metallforschung, Heisenbergstrasse. 3, D-70569 Stuttgart, Germany

J. Strempfer and H.-U. Habermeier

Max-Planck-Institut für Festkörperforschung, Heisenbergstrasse 1, D-70569 Stuttgart, Germany

D. V. Shantsev, Y. M. Galperin, and T. H. Johansen

Department of Physics, University of Oslo, P.O. Box 1048, Blindern, 0316 Oslo, Norway

Anisotropic penetration of magnetic flux in MgB_2 films grown on vicinal sapphire substrates is investigated using magneto-optical imaging. Regular penetration above 10 K proceeds more easily along the substrate surface steps, the anisotropy of the critical current being 6%. At lower temperatures the penetration occurs via abrupt dendritic avalanches that preferentially propagate perpendicular to the surface steps. This inverse anisotropy in the penetration pattern becomes dramatic very close to 10 K where all flux avalanches propagate in the strongest pinning direction. The observed behavior is fully explained using a thermomagnetic model of the dendritic instability.

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Above the lower critical field H_{c1} magnetic flux penetrates type-II superconductors in the form of quantized vortices. Usually, this penetration takes place as a regular flow leading to a smooth flux front [1]. However, in some superconducting films, e.g., of MgB_2 a dramatic flux instability can occur resulting in an abrupt formation of magnetic dendrites [2]. The flux instability is believed to arise because the motion of flux lines dissipates energy leading to local heating, which results in a reduction of pinning and an enhancement of flux line mobility. This constitutes a positive feedback loop which acts as driving force for the avalanches [3,4]. Understanding and controlling the avalanches is important not only from the fundamental point of view, but also for applications since they represent huge magnetic noise and reduce the effective critical current density.

Recently, numerous experimental investigations have demonstrated that the dendritic instability is sensitive to external conditions. The instability was found to disappear above threshold values of temperature [2], applied magnetic field [5], and also for sufficiently small sample dimensions [6]. Also covering MgB_2 films with a layer of gold or aluminum was seen to suppress the dendrite formation [7] or change their propagation direction [8].

To what extent the dendritic instability is sensitive to the internal structure and flux pinning properties of the superconducting film is an important and yet open question. A recent thermomagnetic model predicts that pinning strength represented by the critical current density j_c controls the onset of the dendritic instability [9,10]. In this Letter we show that MgB_2 films with slightly anisotropic j_c can exhibit large anisotropy in the avalanche activity, in full agreement with the model. The result gives direct evidence that the microstructure of chemically homoge-

neous films grown on vicinal substrates defines a direction for dendritic flux propagation, which surprisingly turns out to be perpendicular to the lowest pinning direction.

Substrate-induced modifications of the pinning properties have successfully been obtained previously in high-temperature superconducting films grown on vicinal substrate surfaces [11,12], and on artificially patterned substrates [13,14]. To create anisotropic pinning in films of MgB_2 we used r-cut Al_2O_3 substrates slightly miscut relative to the $[1 -1 0 2]$ direction. The substrate then possesses a surface step structure which can be characterized by two angles $\Delta\theta$ and $\Delta\phi$, according to the sketch in Fig. 1.
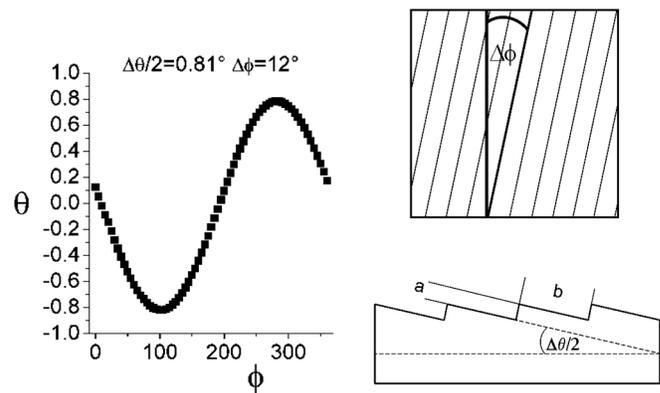

FIG. 1. (Left) X-ray diffraction data for a sapphire substrate slightly miscut with respect to the $[1 -1 0 2]$ direction. (Right) Sketch of the square substrate with surface steps. The angle $\Delta\theta$ defines the deviation from the $[1 -1 0 2]$ surface, $\Delta\phi$ describes the orientation of the steps with respect to the substrate edge, which is equivalent to the 0° orientation of the diffractometer.

Shown in the graph is the result of x-ray diffraction
measurements obtained from surface reflection of a sub-
strate mounted parallel to the ϕ axis of a 4-circle diffrac-
tometer. The deviation θ of the direction of the $[1 \ -1 \ 0 \ 2]$
reflection from the bisecting position is plotted as function
of the angle ϕ. From the curve it follows that the substrate
misorientation angles are $\Delta\theta/2 = 0.81°$ and $\Delta\phi = 12°$.
With a step height of one unit cell a of Al_2O_3, the step
distance becomes $b = a/\tan(\Delta\theta/2) \approx 27$ nm. This dis-
tance was chosen a few times larger than the coherence
length to obtain independent vortex-core pinning by neigh-
boring steps.

The MgB_2 films were grown by sequential deposition of
magnesium and boron layers using a conventional electron
beam evaporation and a subsequent annealing process
[15,16]. The films selected for this study had a lateral
size of 5×5 mm^2, a thickness of 200 nm, and the critical
temperature of 35 K [17]. The magnetic flux penetration
into these films was investigated using the magneto-optical
(MO) Faraday effect allowing direct visualization of the
flux distribution [1]. In our images the brightness repre-
sents the magnitude of the flux density.

To measure the anisotropy of the critical current density
the sample was first cooled to 12 K, and then exposed to a
large magnetic field which was subsequently removed. In
this remanent state, seen in Fig. 2, the flux distribution
develops a set of bright discontinuity lines (d lines), where
the current sharply bends to adapt to the shape of the
sample [18]. In an isotropic film the angle between the d
lines and the edge would be 45° and the d lines would meet

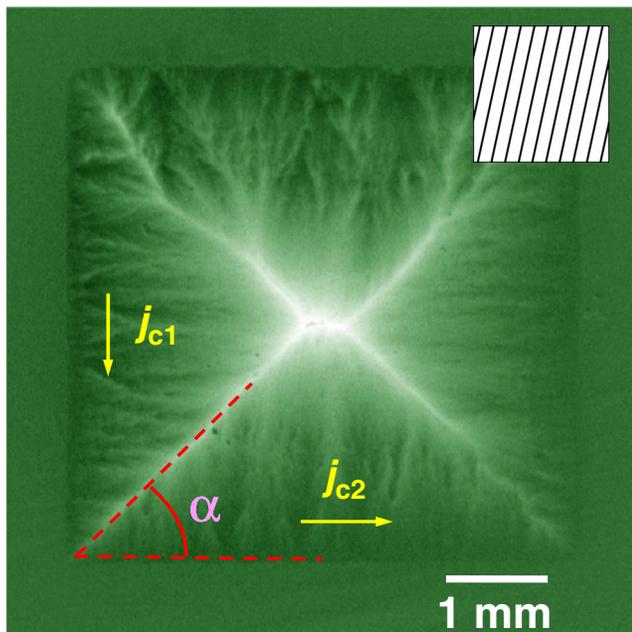in the center of the square. In our samples this is not the
case, as seen directly by the presence of a horizontal bright
line segment in the central part of the square. Evidently, the
current flowing parallel to the vertical edges gives stronger
shielding than the current flowing horizontally. Assuming
Bean-model behavior [19], the two critical current den-
sities j_{c1} and j_{c2} are related to the d line angle α, see the
figure, by $j_{c1}/j_{c2} = \tan\alpha$. Measurement of the angle gives
$\tan\alpha = 1.06$, i.e., a 6% anisotropy. Comparing with the
direction of the steps on the substrate surface, see Fig. 1,
the larger value of j_{c1} represents a pinning force enhance-
ment for flux moving perpendicular to the surface steps.
We did not detect any temperature dependence of the j_c
anisotropy in the 8–12 K range.

Shown in Fig. 3 is the flux distribution after applying a
8 mT magnetic field to the MgB_2 film initially zero-field
cooled to the slightly lower temperatures. Here one should
expect the flux to penetrate in the form of dendritic ava-
lanches [2], which indeed is what we observe. At 8 K the
avalanches are seen to enter the film evenly from all the
edges. At 10 K, however, the penetration pattern suddenly
becomes strongly anisotropic; flux dendrites develop from
the vertical edges only, whereas from the top and bottom
edges the penetration is smooth. In other words, the flux
dendrites propagate predominantly in the direction perpen-
dicular to the substrate surface steps, i.e., the direction of
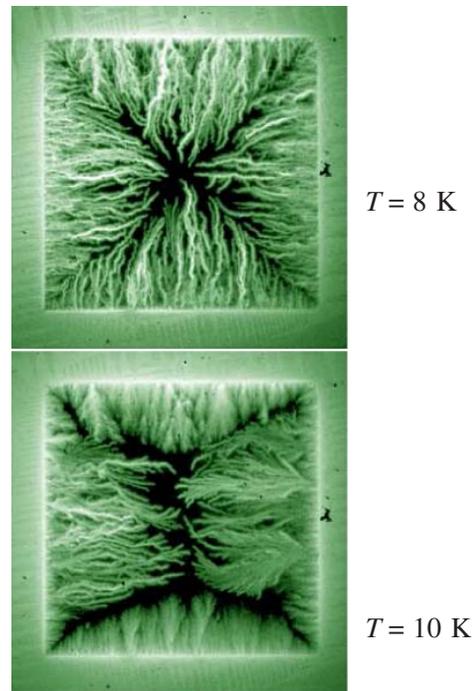the stronger flux pinning. It is indeed highly counterintui-

FIG. 2 (color online). Magneto-optical image of the remanent
state in an anisotropic 5×5 mm^2 MgB_2 film at 12 K. The angle
α indicates the orientation of the discontinuity line which allows
determination of the critical current density ratio j_{c1}/j_{c2}.

FIG. 3 (color online). Flux penetration into the same MgB_2
film as in Fig. 2, but at lower temperatures and an applied field of
16 mT. At 8 K the flux pattern is dendritic and isotropic, while at
10 K dendritic avalanches are formed only along one direction.

tive that the flux prefers to move perpendicular rather than parallel to the linear defects introduced in the sample.

A quite similar behavior was observed for the penetration behavior during field descent, see Fig. 4. The images show the remanent state after applying a maximum field of $\mu_0 H = 0.2$ T. Again at 8 K, the penetration is isotropic only now the dendrites appear dark since they consist of antiflux surrounded by annihilation zones. At 10 K the dendrites propagate also now along the horizontal direction dictated by the microstructural anisotropy. The d line pattern at 10 K indicates an anisotropy opposite to that in Fig. 2, showing again that the anisotropy in the flux propagation is opposite to what is expected from the anisotropy in pinning, i.e., j_c.

All these experiments show the remarkable fact that an anisotropy in j_c as small as 6% can lead to a dramatic anisotropy in the avalanche activity near 10 K, and only very near this temperature. This behavior can be understood using results of a recent model of the dendritic instability developed in Refs. [9,10]. The model is based on stability analysis of the thermal diffusion and Maxwell equations in a long and thin superconducting strip thermally coupled to a substrate. Initially, the strip is placed in an increasing perpendicular magnetic field, and a Bean-like critical state is formed in the flux penetrated region. This state can become unstable with respect to perturbations in the magnetic field and temperature, and under some conditions a fastest growing perturbation has a non-

$T = 8$ K

$T = 10$ K

FIG. 4 (color online). Remanent states of the anisotropic MgB$_2$ film. The flux pattern is isotropic at 8 K, but strongly anisotropic at 10 K, similar to the virgin penetration behavior in Fig. 3.

zero wave vector along the film edge. This means that an instability will develop in the form of narrow fingers perpendicular to the edge—a scenario closely resembling the observed dendritic flux behavior. The threshold flux penetration depth ℓ^* when the superconducting strip first becomes unstable is given by Eq. (25) of Ref. [9], which can be written as

$$\ell^* = \frac{\pi}{2}\sqrt{\frac{\kappa T^*}{j_c E}}\left(1 - \sqrt{\frac{2h_0 T^*}{n d j_c E}}\right)^{-1}. \tag{1}$$

Here, d is the film thickness, $T^* \equiv -(\partial \ln j_c/\partial T)^{-1}$, κ is the thermal conductivity, and h_0 is the coefficient of heat transfer from the superconducting film to the substrate. The parameter n characterizes the nonlinearity of the current-voltage curve of the superconductor, $n = \partial \ln E/\partial \ln j \gg 1$.

The threshold field H_{th}, when the first dendrite invades the film, is obtained by combining (1) with the Bean-model expression,

$$H = \frac{j_c d}{\pi}\mathrm{arccosh}\left(\frac{w}{w - \ell}\right), \tag{2}$$

which connects the applied field with the flux penetration depth ℓ for a long thin strip of width $2w$ [19].

Figure 5 shows the dependence of H_{th} on j_c calculated using Eqs. (1) and (2) assuming $\kappa T^*/E = 140$ A and $h_0 T^*/nE = 9230$ A/m (which can mean, e.g., $T^* = 10$ K, $E = 10$ mV/m, $\kappa = 0.14$ W/K m, $n = 30$, and $h_0 = 280$ W/K m^2). For high critical currents the threshold field is weakly dependent on j_c. However, when j_c becomes smaller, the expression in the brackets of Eq. (1) approaches zero, and H_{th} diverges. When j_c drops below a certain value, the dendritic instability is absent no matter how large of a field is applied.

The critical current density at 10 K can be estimated using Eq. (2) from the flux penetration depth just before the avalanche behavior sets in. We then find $j_{c2} = 1 \times 10^{11}$ A/m^2, and j_{c1} larger by 6%. These critical current values found from MO images agree with results obtained by SQUID measurements [16]. The two values for j_c are indicated by two dashed lines in Fig. 5. Despite the small difference between j_{c1} and j_{c2}, the corresponding threshold fields H_{th1} and H_{th2} differ significantly. When the increasing applied field reaches the lowest of the two threshold fields, H_{th1}, the dendrites should appear from the sides where j_c is the highest. This is exactly what one can see from Fig. 3 (bottom). Interestingly, this penetration pattern dominated by dendrites shows an inverted anisotropy compared to the critical state pattern in Fig. 2.

As the applied field is further increased and reaches H_{th2}, one could expect that dendrites appear also from the top and bottom edges. However, this does not happen experimentally. The reason probably is the dramatic disturbance in the current flow created by the dendritic structures formed at the smaller fields. They fill almost the whole
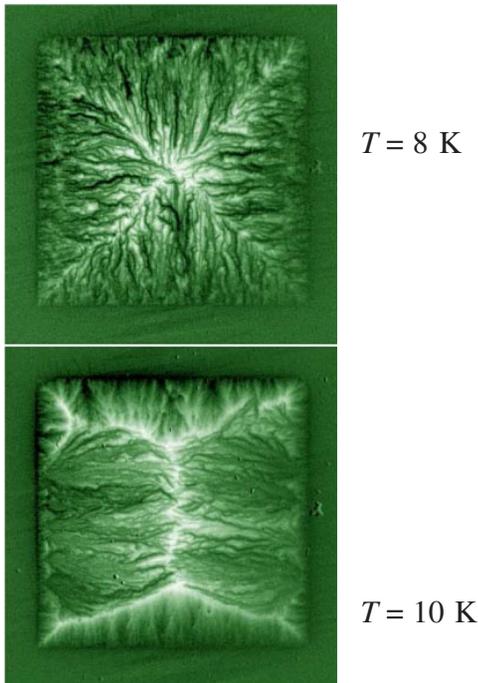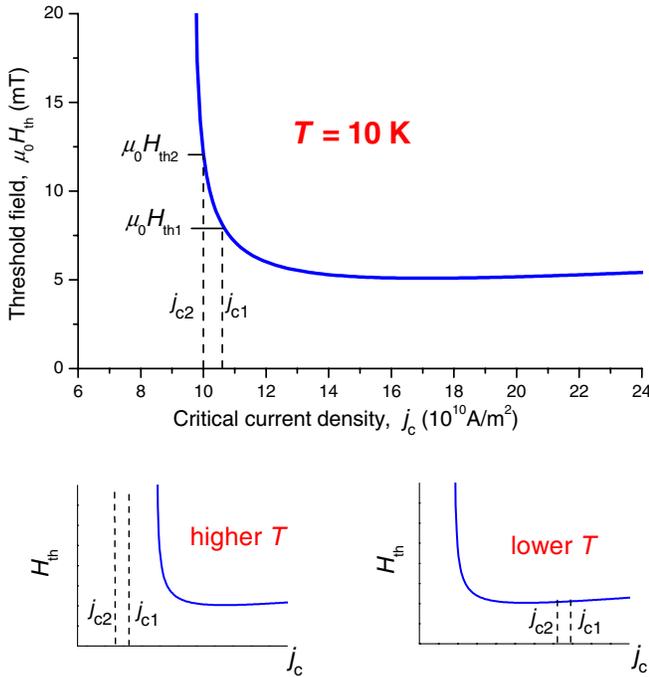
FIG. 5 (color online). Big plot: Threshold field for the dendritic instability as a function of the critical current density, calculated using (1) and (2). Two dashed lines show the values of j_c in an MgB_2 film at 10 K for the directions along and across the substrate steps. Large difference in the corresponding H_{th}'s implies a strong anisotropy of the dendritic avalanches specifically at $T = 10$ K. Two small plots illustrate the behavior at higher temperatures (there is no instability) and lower temperatures (isotropic instability, $H_{th1} \approx H_{th2}$).

interior of the film, thus lowering the edge fields substantially, which prevents invasion of new dendrites.

At a higher temperature, the critical current density becomes smaller; i.e., we "move" to the left along the x axis in Fig. 5, and enter the stable region. This is again in full agreement with experiment, where we do not observe dendritic avalanches above 10 K. Conversely, by lowering the temperature we move to the right, where H_{th} is almost independent of j_c. Hence, the dendritic avalanches should penetrate evenly from all four sides of the square film. This is exactly what we find at 8 K; see Fig. 4 (top), and at lower T [20].

Note that the $H_{th}(j_c)$ curve is slowly rising at large j_c. It means that at very low T one should expect the opposite kind of anisotropy in the dendritic growth. Namely, the dendrites should first appear from the sides where the regular flux penetration is deeper. However, in order to observe this effect one needs a sample where the anisotropy in j_c is much stronger than the 6% in the present case.

The analysis above shows that the dendritic penetration has a pronounced anisotropy only in the narrow interval of temperatures corresponding to the steep region at the $H_{th}(j_c)$ curve. For other superconducting samples this region will not necessarily be located at 10 K, but it will always be near the threshold temperature above which the instability disappears.

In conclusion, we have investigated the magnetic flux penetration into MgB_2 films grown on vicinal sapphire substrates. The resulting microstructure giving a slight anisotropy in j_c leads to a large anisotropy in the flux patterns, but only in a narrow temperature interval near 10 K. Here, the dendritic avalanches propagate only in the direction perpendicular to the substrate surface steps; i.e., the flux moves along the direction of largest pinning. The surprising behavior is fully explained by a thermomagnetic model for the dendritic instability.

*Present address: Chemistry Department, Lomonosov MSU, 119992 Moscow, Russia.
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[20] Note that κ and h_0 increase with temperature. For $T > 10$ K this shifts the $H_{th}(j_c)$ curve to the right, while for $T < 10$ K—to the left. This produces the same relative shifts as the T dependence of j_c, and hence does not change our conclusions.